

SLPS208A - AUGUST 2009 - REVISED SEPTEMBER 2010

N-Channel NexFET[™] Power MOSFET

Check for Samples: CSD16414Q5

FEATURES

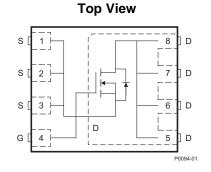
- Ultra Low Qg and Qgd
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5mm × 6mm Plastic Package

APPLICATIONS

- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and Computing Systems
- Optimized for Synchronous FET Applications

DESCRIPTION

The NexFET[™] power MOSFET has been designed to minimize losses in power conversion applications.



R_{DS(ON)} vs V_{GS} 6 12 R_{DS(on)} – On-State Resistance – mΩ $I_{D} = 30A$ 5 10 V_G – Gate Voltage – V 8 4 $T_C = 125^{\circ}C$ 3 6 2 4 1 2 = 25°C T_C 0 0 0 2 4 6 8 10 12 0 V_{GS} - Gate to Source Voltage - V G006

PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage	25	V	
Qg	Gate Charge Total (4.5V) 16.6			
Q_{gd}	Gate Charge Gate to Drain	4.4	nC	
Б	Drain to Source On Desistance	$V_{GS} = 4.5V$	2.1	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 10V$	1.5	mΩ
V _{GS(th)}	Threshold Voltage 1.6			

ORDERING INFORMATION

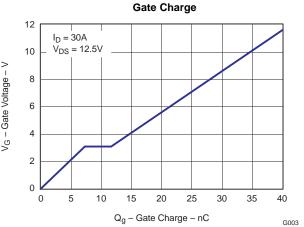
Device	Package	Media	Qty	Ship
CSD16414Q5	SON 5 × 6 Plastic Package	13-inch reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

T _A = 2	T _A = 25°C unless otherwise stated VALUE UN						
V_{DS}	Drain to Source Voltage	25	V				
V_{GS}	Gate to Source Voltage	+16 / -12	V				
	Continuous Drain Current, T _C = 25°C	100	А				
I _D	Continuous Drain Current ⁽¹⁾	34	А				
I _{DM}	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	213	А				
PD	Power Dissipation ⁽¹⁾	3.2	W				
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C				
E _{AS}	Avalanche Energy, single pulse $I_D = 100A$, L = 0.1mH, $R_G = 25\Omega$	500	mJ				

(1) $R_{\theta JA} = 39^{\circ}C/W$ on $1in^2$ Cu (2 oz.) on 0.060" thick FR4 PCB.

(2) Pulse width \leq 300 μ s, duty cycle \leq 2%"



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ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Static Ch	naracteristics				
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	25		V
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 20V$		1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +16/-12V$		100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.3 1.6	2	V
D	Drain to Source On Desistance	$V_{GS} = 4.5V, I_{D} = 30A$	2.1	2.6	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 10V, I_D = 30A$	1.5	1.9	mΩ
9 _{fs}	Transconductance	V _{DS} = 15V, I _D = 30A	138		S
Dynamic	Characteristics	· · · ·		1	
C _{ISS}	Input Capacitance		2810	3650	pF
C _{OSS}	Output Capacitance	V _{GS} = 0V, V _{DS} = 12.5V, f = 1MHz	2040	2650	pF
C _{RSS}	Reverse Transfer Capacitance		140	180	pF
R _g	Series Gate Resistance		1.4	2.8	Ω
Qg	Gate Charge Total (4.5V)		16.6	21	nC
Q _{gd}	Gate Charge Gate to Drain		4.4		nC
Q _{gs}	Gate Charge Gate to Source	V _{DS} = 12.5V, ID = 30A	7.3		nC
Qg(th)	Gate Charge at Vth		4.5		nC
Q _{OSS}	Output Charge	V _{DS} = 13.5V, VGS = 0V	40		nC
t _{d(on)}	Turn On Delay Time		15		ns
t _r	Rise Time	V _{DS} = 12.5V, V _{GS} = 4.5V, I _D = 30A	24		ns
t _{d(off)}	Turn Off Delay Time	$R_{\rm G} = 2\Omega$	18.4		ns
t _f	Fall Time		11.1		ns
Diode Ch	haracteristics	+			
V _{SD}	Diode Forward Voltage	$I_{\rm S} = 30$ A, $V_{\rm GS} = 0$ V	0.81	1	V
Q _{rr}	Reverse Recovery Charge	V _{dd} = 13.5V, I _F = 30A, di/dt = 300A/µs	44		nC
t _{rr}	Reverse Recovery Time	V _{dd} = 13.5V, I _F = 30A, di/dt = 300A/µs	35		ns

THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	MIN	TYP	MAX	UNIT
R _{0JC}	Thermal Resistance Junction to Case ⁽¹⁾			1.1	°C/W
R _{0JA}	Thermal Resistance Junction to Ambient ^{(1) (2)}			50	°C/W

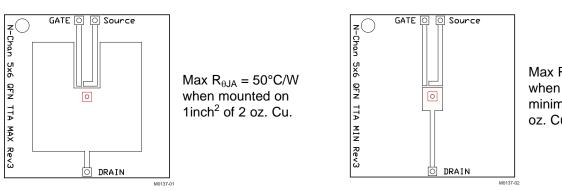
(1) R $_{\theta JC}$ is determined with the device mounted on a 1 inch square 2 oz. Cu pad on a 1.5 x 1.5 in 0.060 inch thick FR4 board. R $_{\theta JC}$ is specified by design while R $_{\theta JA}$ is determined by the user's board design.

(2) Device mounted on FR4 Material with 1 inch² of 2 oz. Cu.



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Max $R_{\theta JA} = 122^{\circ}C/W$ when mounted on minimum pad area of 2 oz. Cu.

TYPICAL MOSFET CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

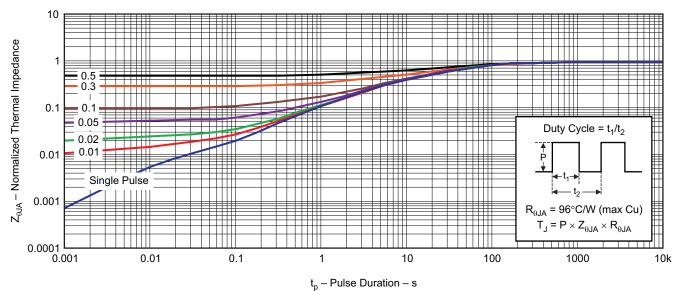


Figure 1. Transient Thermal Impedance

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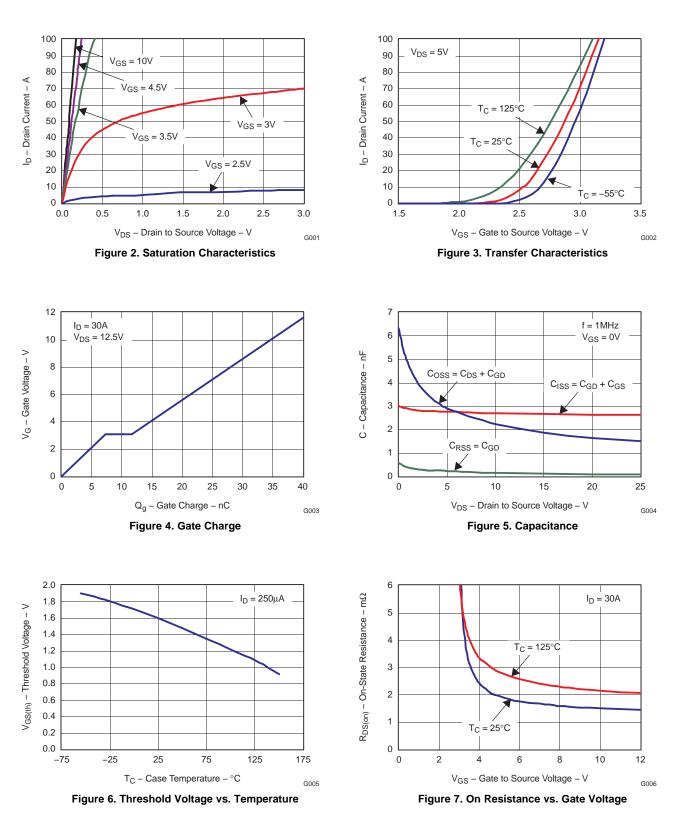
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ISTRUMENTS

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TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$



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TYPICAL MOSFET CHARACTERISTICS (continued)

$(T_A = 25^{\circ}C \text{ unless otherwise stated})$

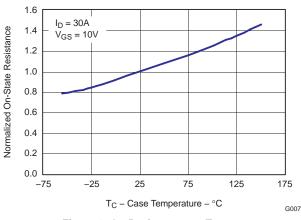


Figure 8. On Resistance vs. Temperature

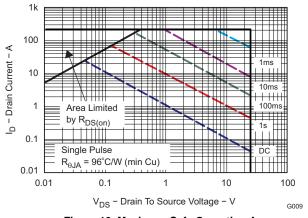


Figure 10. Maximum Safe Operating Area

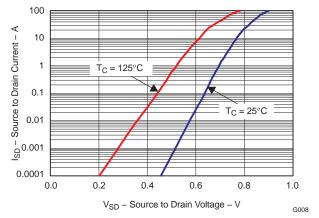


Figure 9. Typical Diode Forward Voltage

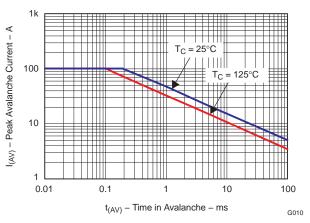
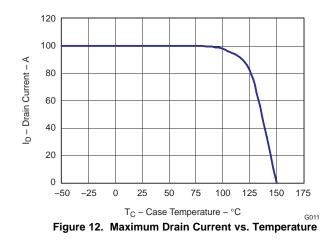


Figure 11. Single Pulse Unclamped Inductive Switching





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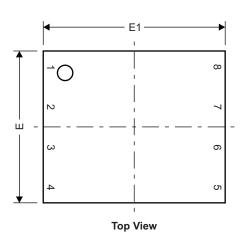
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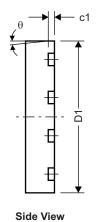
K ← L

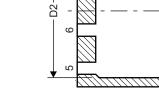
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MECHANICAL DATA

Q5 Package Dimensions





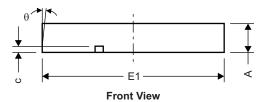


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Bottom View

E2



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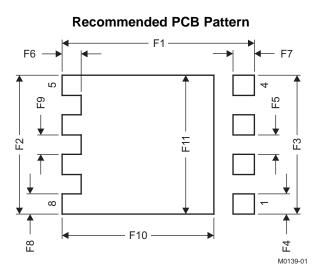
DIM	MILLIM	ETERS	INCHES			
DIW	MIN	MAX	MIN	MAX		
A	0.950	1.050	0.037	0.039		
b	0.360	0.460	0.014	0.018		
С	0.150	0.250	0.006	0.010		
c1	0.150	0.250	0.006	0.010		
D1	4.900	5.100	0.193	0.201		
D2	4.320 4.520		0.170	0.178		
E	4.900 5.100		0.193	0.201		
E1	5.900	6.100	0.232	0.240		
E2	2 3.920 4.12 0.154		0.154	0.162		
е	1.27	TYP	0.0)50		
К	0.760		0.030			
L	0.510	0.710	0.020	0.028		
θ	0.00					



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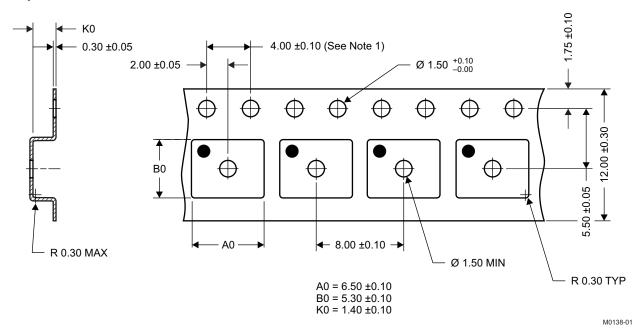
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DIM	MILLIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.460	4.560	0.176	0.180
F3	4.460	4.560	0.176	0.180
F4	0.650	0.700	0.026	0.028
F5	0.620	0.670	0.024	0.026
F6	0.630	0.680	0.025	0.027
F7	0.700	0.800	0.028	0.031
F8	0.650	0.700	0.026	0.028
F9	0.620	0.670	0.024	0.026
F10	4.900	5.000	0.193	0.197
F11	4.460	4.560	0.176	0.180

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q5 Tape and Reel Information



Notes:

- 1. 10 sprocket hole pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm IN 100mm, noncumulative over 250mm
- 3. Material:black static dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. Thickness: 0.30 ±0.05mm
- 6. MSL1 260°C (IR and Convection) PbF Reflow Compatible

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REVISION HISTORY

С	hanges from Original (August 2009) to Revision A	Page
•	Deleted the Package Marking Information section	7



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10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
CSD16414Q5	ACTIVE	VSON-CLIP	DQH	8	2500	RoHS-Exempt & Green	SN	Level-1-260C-UNLIM	-55 to 150	CSD16414	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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